

RELIABILITY REPORT  
FOR  
MAX13047EETA+  
PLASTIC ENCAPSULATED DEVICES

July 31, 2009

**MAXIM INTEGRATED PRODUCTS**

120 SAN GABRIEL DR.  
SUNNYVALE, CA 94086

<b>Approved by</b>
Ken Wendel
Quality Assurance
Director, Reliability Engineering

## Conclusion

The MAX13047EETA+ successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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### I. Device Description

#### A. General

The MAX13046E/MAX13047E  $\pm 15\text{kV}$  ESD-protected bidirectional level translators provide level shifting for data transfer in a multivoltage system. The MAX13046E is a single-channel translator, and the MAX13047E is a dual-channel translator. Externally applied voltages, VCC and VL, set the logic level on either side of the device. The MAX13046E/MAX13047E utilize a transmission-gate-based design to allow data translation in either direction (V L &#8660; VCC) on any single data line. The MAX13046E/MAX13047E accept VL from +1.1V to the minimum of either +3.6V or (VCC + 0.3V), and VCC from +1.65V to +5.5V, making these devices ideal for data transfer between low-voltage ASICs/PLDs and higher voltage systems. The MAX13046E/MAX13047E feature a shutdown mode that reduces supply current to less than 1 $\mu\text{A}$  thermal short-circuit protection, and  $\pm 15\text{kV}$  ESD protection on the VCC side for enhanced protection in applications that route signals externally. The MAX13046E/MAX13047E operate at a guaranteed data rate of 8Mbps when push-pull driving is used. The MAX13046E is available in a 6-pin  $\mu\text{DFN}$  package, and the MAX13047E is available in a 10-pin UTQFN. Both devices are specified over the extended  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$  operating temperature range.

## II. Manufacturing Information

A. Description/Function:	Single- and Dual-Channel, Bidirectional Low-Level Translators
B. Process:	S4
C. Number of Device Transistors:	
D. Fabrication Location:	California, Texas or Japan
E. Assembly Location:	Thailand, Malaysia
F. Date of Initial Production:	July 26, 2008

## III. Packaging Information

A. Package Type:	8-pin TDFN 2x2
B. Lead Frame:	Copper
C. Lead Finish:	100% matte Tin
D. Die Attach:	Conductive
E. Bondwire:	Au (1 mil dia.)
F. Mold Material:	Epoxy with silica filler
G. Assembly Diagram:	#05-9000-3025
H. Flammability Rating:	Class UL94-V0
I. Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C	Level 1
J. Single Layer Theta Jc:	10.8°C/W
K. Multi Layer Theta Ja:	83.9°C/W
L. Multi Layer Theta Jc:	36.6°C/W

## IV. Die Information

A. Dimensions:	30 X 30 mils
B. Passivation:	Si <sub>3</sub> N <sub>4</sub> /SiO <sub>2</sub> (Silicon nitride/ Silicon dioxide)
C. Interconnect:	Al with Ti/TiN Barrier
D. Backside Metallization:	None
E. Minimum Metal Width:	Metal1 = 0.5 / Metal2 = 0.6 / Metal3 = 0.6 microns (as drawn)
F. Minimum Metal Spacing:	Metal1 = 0.45 / Metal2 = 0.5 / Metal3 = 0.6 microns (as drawn)
G. Bondpad Dimensions:	5 mil. Sq.
H. Isolation Dielectric:	SiO <sub>2</sub>
I. Die Separation Method:	Wafer Saw

## V. Quality Assurance Information

- A. Quality Assurance Contacts: Ken Wendel (Director, Reliability Engineering)  
Bryan Preeshl (Managing Director of QA)
- B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.  
0.1% For all Visual Defects.
- C. Observed Outgoing Defect Rate: < 50 ppm
- D. Sampling Plan: Mil-Std-105D

## VI. Reliability Evaluation

### A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate ( $\lambda$ ) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{192 \times 4340 \times 48 \times 2} \quad (\text{Chi square value for MTTF upper limit})$$

(where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV)

$$\lambda = 22.4 \times 10^{-9}$$

$\lambda = 22.4$  F.I.T. (60% confidence level @ 25°C)

The following failure rate represents data collected from Maxim's reliability monitor program. Maxim performs quarterly 1000 hour life test monitors on its processes. This data is published in the Product Reliability Report found at <http://www.maxim-ic.com/>. Current monitor data for the S4 Process results in a FIT Rate of 4.6 @ 25C and 79.2 @ 55C (0.8 eV, 60% UCL)

### B. Moisture Resistance Tests

The industry standard 85°C/85%RH or HAST testing is monitored per device process once a quarter.

### C. E.S.D. and Latch-Up Testing

The LT10 die type has been found to have all pins able to withstand a HBM transient pulse of +/-2500 V per JEDEC JESD22-A114. Latch-Up testing has shown that this device withstands a current of +/-250 mA, 1.5x VCCMax Overvoltage per JESD78.

**Table 1**  
Reliability Evaluation Test Results

**MAX13047EETA+**

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES
<b>Static Life Test</b> (Note 1)	Ta = 135°C Biased Time = 192 hrs.	DC Parameters & functionality	48	0
<b>Moisture Testing</b> (Note 2) 85/85	Ta = 85°C RH = 85% Biased Time = 1000hrs.	DC Parameters & functionality	77	0
<b>Mechanical Stress</b> (Note 2) Temperature Cycle	-65°C/150°C 1000 Cycles Method 1010	DC Parameters & functionality	77	0

Note 1: Life Test Data may represent plastic DIP qualification lots.

Note 2: Generic Package/Process data